SPS

The SPS product family is specially designed for an off-line SMPS with minimal external components. The SPS consist of high voltage power SenseFET and current mode PWM IC. Included PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, and temperature compensated precision current sources for loop compensation and fault protection circuitry. Compared to discrete MOSFET and controller or RCC switching converter solution, a SPS can reduce total component count, design size, weight and at the same time increase efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.

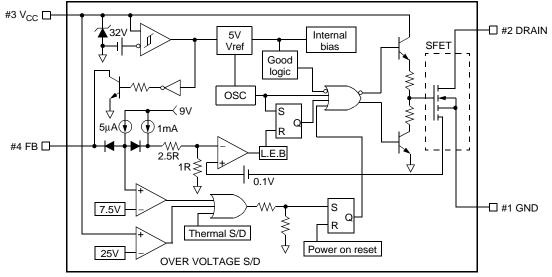
FEATURES

- Precision fixed operating frequency (50kHz)
- Pulse by pulse over current limiting
- Over Current Protection
- Over Voltage Protection (Min. 23V)
- Internal thermal shutdown function
- Under voltage lockout
- Internal high voltage sense FET
- Latch up mode

TO-220F-4L

ORDERING INFORMATION

Device	Package	Operating Temperature
KA1L0380	TO-220F-4L	–25°C to +85°C





BLOCK DIAGRAM

1

ABSOLUTE MAXIMUM RATINGS

Characteristic	Symbol	Value	Unit	
Drain-source (GND) voltage ⁽¹⁾	V _{DSS}	800	V	
Drain-Gate voltage (R_{GS} =1M Ω)	V _{DGR}	800	V	
Gate-source (GND) voltage	V _{GS}	±30	V	
Drain current pulsed ⁽²⁾	I _{DM}	12	A _{DC}	
Single pulsed avalanche energy ⁽³⁾	E _{AS}	95	mJ	
Avalanche current ⁽⁴⁾	I _{AS}	-	А	
Continuous drain current (T _C =25°C)	I _D	3.0	A _{DC}	
Continuous drain current (T _C =100°C)	I _D	2.1	A _{DC}	
Supply voltage	V _{CC}	30	V	
Analog input voltage range	V _{FB}	-0.3 to V _{SD}	V	
Total power dissipation	P _D (watt H/S)	35	W	
	Derating	0.28	W/°C	
Operating temperature	T _{OPR}	-25 to +85	°C	
Storage temperature	T _{STG}	-55 to +150	٥C	

NOTES:

- 1. Tj=25°C to 150°C
- 2. Repetitive rating: Pulse width limited by maximum junction temperature
- 3. L=41mH, V_{DD} =50V, R_G=25 Ω , starting Tj=25°C





ELECTRICAL CHARACTERISTICS (SFET part)

(Ta=25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Тур.	Max.	Unit
Drain-source breakdown voltage	BV _{DSS}	V _{GS} =0V, I _D =50μA	800	_	_	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =Max., Rating, V _{GS} =0V	_	_	50	μΑ
		V _{DS} =0.8Max., Rating, V _{GS} =0V, T _C =125°C	-	_	200	μA
Static drain-source on resistance (note)	R _{DS(ON)}	V _{GS} =10V, I _D =1.5A	_	4.0	5.0	Ω
Forward transconductance (note)	gfs	V _{DS} =15V, I _D =1.5A	1.5	2.5	_	mho
Input capacitance	Ciss	V _{GS} =0V, V _{DS} =25V,	_	779	_	pF
Output capacitance	Coss	f=1MHz	_	75.6	-	
Reverse transfer capacitance	Crss		_	24.9	-	
Turn on delay time	td(on)	V _{DD} =0.5BV _{DSS} , I _D =3.0A (MOSFET switching time are essentially independent of	-	40	-	nS
Rise time	tr		_	95	-	
Turn off delay time	td(off)		_	150	-	
Fall time	tf	operating temperature)	_	60	-	
Total gate charge (gate-source+gate-drain)	Qg	V_{GS} =10V, I _D =3.0A, V_{DS} =0.5B V_{DSS} (MOSFET switching time are essentially independent of	_	_	34	nC
Gate-source charge	Qgs		-	7.2	-	
Gate-drain (Miller) charge	Qgd	operating temperature)	—	12.1	-	

NOTE: Pulse test: Pulse width $\leq 300\mu S$, duty cycle $\leq 2\%$



ELECTRICAL CHARACTERISTICS (Control part)

(Ta=25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Тур.	Max.	Unit
REFERENCE SECTION						
Output voltage ⁽¹⁾	Vref	Ta=25°C	4.80	5.00	5.20	V
Temperature Stability ⁽¹⁾⁽²⁾	Vref/∆T	–25°C≤Ta≤+85°C	-	0.3	0.6	mV/°C
OSCILLATOR SECTION						
Initial accuracy	F _{OSC}	Ta=25°C	45	50	55	kHz
Frequency change with temperature ⁽²⁾	$\Delta F / \Delta T$	–25°C≤Ta≤+85°C	-	±5	±10	%
PWM SECTION						
Maximum duty cycle	Dmax	-	74	77	80	%
FEEDBACK SECTION	1					
Feedback source current	I _{FB}	Ta=25°C, 0V≤Vfb≤3V	0.7	0.9	1.1	mA
Shutdown delay current	Idelay	Ta=25°C, 5V≤Vfb≤V _{SD}	4.0	5.0	6.0	μΑ
OVER CURRENT PROTECTION SECT	ION					
Over current protection	I _L (max)	Max. inductor current	1.89	2.15	2.41	Α
UVLO SECTION						1
Start threshold voltage	Vth(H)	-	14	15	16	V
Minimum operating voltage	Vth(L)	After turn on	9	10	11	V
TOTAL STANDBY CURRENT SECTION	N					
Start current	I _{ST}	V _{CC} =14V	0.1	0.3	0.45	mA
Operating supply current (control part only)	I _{OPR}	Ta=25°C	6	12	18	mA
V _{CC} zener voltage	VZ	I _{CC} =20mA	30	32.5	35	V
SHUTDOWN SECTION						
Shutdown Feedback voltage	V _{SD}	-	6.9	7.5	8.1	V
Thermal shutdown temperature (Tj) ⁽¹⁾	T _{SD}	-	140	160	_	°C
Over voltage protection voltage	V _{OVP}	-	23	25	28	V

NOTES:

1. These parameters, although guaranteed, are not 100% tested in production

2. These parameters, although guaranteed, are tested in EDS (wafer test) process



TYPICAL PERFORMANCE CHARACTERISTICS

(These characteristic graphs are normalized at Ta=25°C)

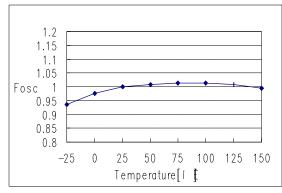


Figure 1. Operating Frequency

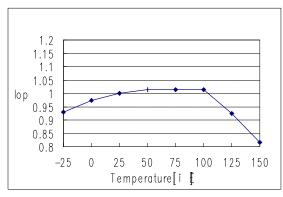


Figure 3. Operating Current

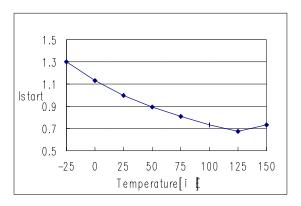


Figure 5. Start up Current

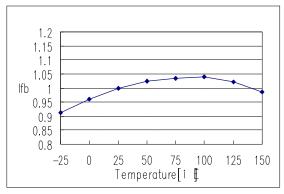


Figure 2. Feedback Source Current

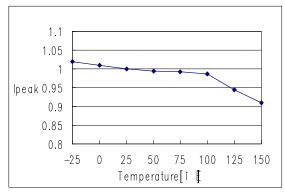


Figure 4. Max. Inductor Current

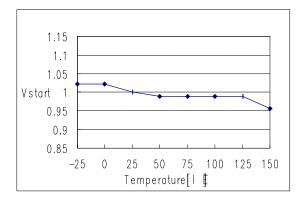


Figure 6. Start Threshold Voltage



TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(These characteristic graphs are normalized at Ta=25°C)

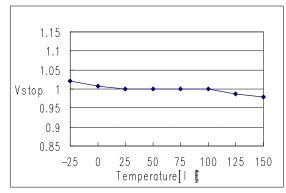


Figure 7. Stop Threshold Voltage

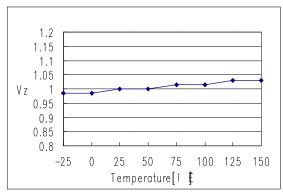


Figure 9. V_{CC} Zener Voltage

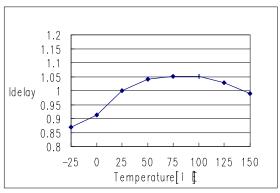


Figure 11. Shutdown Delay Current

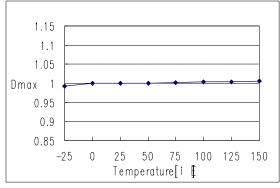


Figure 8. Maximum Duty Cycle

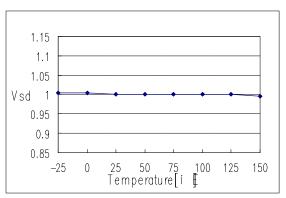


Figure 10. Shutdown Feedback Voltage

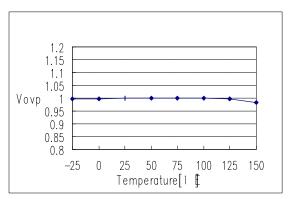


Figure 12. Over Voltage Protection



TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(These characteristic grahps are normalized at Ta=25°C)

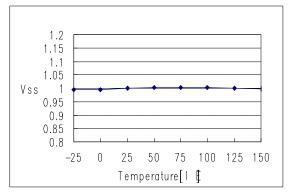
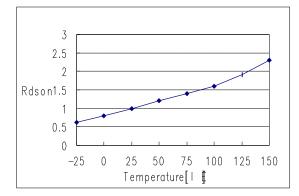


Figure 13. Soft Start Voltage





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